

# **isc Silicon NPN Power Transistor**

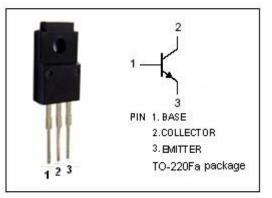
# 2SD1585

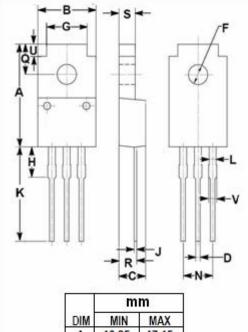
### DESCRIPTION

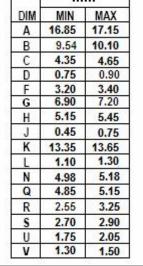
- High Collector Current:: Ic= 3A
- Low Collector Saturation Voltage
  : V<sub>CE(sat)</sub>= 1.5V(Max)@I<sub>C</sub>= 2A
- Complement to Type 2SB1094
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

## APPLICATIONS

 Designed for power supplies or a variety of drives in audio and other equipment.







## ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>CBO</sub>	Collector-Base Voltage	60	V	
V <sub>CEO</sub>	Collector-Emitter Voltage	60	V	
V <sub>EBO</sub>	Emitter-Base Voltage	7	V	
lc	Collector Current-Continuous	3	A	
Ісм	Collector Current-Peak	5	А	
I <sub>B</sub>	Base Current-Continuous	0.6	А	
Pc	Total Power Dissipation @ T₂=25℃	2		
	Total Power Dissipation @ T <sub>c</sub> =25℃	15	W	
TJ	Junction Temperature	150	ĉ	
T <sub>stg</sub>	Storage Temperature Range	-55~150	°C	

isc website: <u>www.iscsemi.com</u>



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## ELECTRICAL CHARACTERISTICS

### $T_{c}\text{=}25^{\circ}\!\!\!\!C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	МАХ	UNIT
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 2A; I <sub>B</sub> = 0.2A			1.5	V
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	I <sub>C</sub> = 2A; I <sub>B</sub> = 0.2A			2.0	V
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = 60V; I <sub>E</sub> = 0			10	μA
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 7V; I <sub>C</sub> = 0			10	μA
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = 50mA; V <sub>CE</sub> = 5V	20			
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = 0.5A; V <sub>CE</sub> = 5V	40		200	
Сов	Output Capacitance	I <sub>E</sub> = 0; V <sub>CB</sub> = 10V; f= 1MHz		48		pF
f⊤	Current-Gain—Bandwidth Product	I <sub>C</sub> = 0.1A; V <sub>CE</sub> = 5V		16		MHz

#### h<sub>FE-2</sub> Classifications

М	L	к
40-80	60-120	100-200

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